

SNx5LBC174A 四路 RS-485 差分线路驱动器

1 特性

- 专为 TIA/EIA-485、TIA/EIA-422 和 ISO 8482 应用而设计
- 信号传输速率¹ 高达 30Mbps
- 传播延迟时间 < 11ns
- 低待机功耗 - 最大 1.5mA
- 输出 ESD 保护：12kV
- 驱动器正负电流限制
- 上电和下电无干扰运行，适用于线路插入应用
- 热关断保护
- 业界通用引脚排列，与 SN75174、MC3487、DS96174、LTC487 和 MAX3042 兼容

2 应用

- 电机驱动器
- 工厂自动化和控制

3 说明

SN65LBC174A 和 SN75LBC174A 是具有三态输出的四通道差分线路驱动器，专为 TIA/EIA-485 (RS-485)、TIA/EIA-422 (RS-422) 和 ISO 8482 应用而设计。

这些器件经优化，能够以高达 30Mbit/s 的信号传输速率实现平衡多点总线传输。此传输介质可以是印刷电路

板走线、底板、或者电缆。最终数据传输速率和距离取决于介质衰减特性和环境噪声耦合。

每个驱动器都具有电流限制和热关断电路，因此适用于嘈杂环境中的高速多点数据传输应用。这些器件采用 LinBiCMOS® 进行设计，有助于实现低功耗和稳健性。

两个使能 (EN) 输入为驱动器提供两个使能端，或可通过外部集成，在单一信号下对所有四个驱动器进行使能控制。禁用或断电后，驱动器输出为总线提供高阻抗，从而降低系统负载。

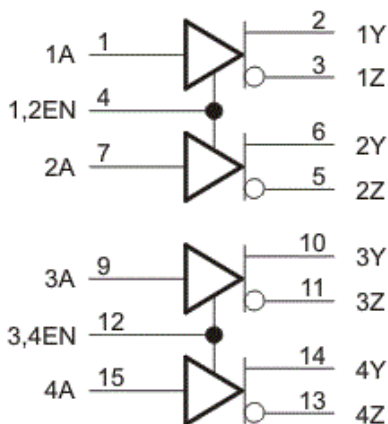
SN75LBC174A 可在 0°C 至 70°C 的工作温度范围内运行。SN65LBC174A 可在 -40°C 至 85°C 的温度范围内运行。

封装信息

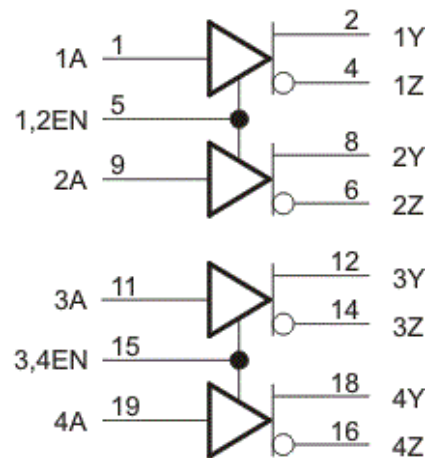
器件型号	封装 ⁽¹⁾	封装尺寸 ⁽²⁾
SN65LBC174A SN75LBC174A	SOIC (DW , 16)	10.3mm x 10.3mm
	SOIC (DW , 20)	12.8mm x 10.3mm
	PDIP (N , 16)	19.3mm x 9.4mm

(1) 有关更多信息，请参阅节 11。

(2) 封装尺寸 (长 × 宽) 为标称值，并包括引脚 (如适用)。



逻辑图 (正逻辑)



逻辑图 (正逻辑)

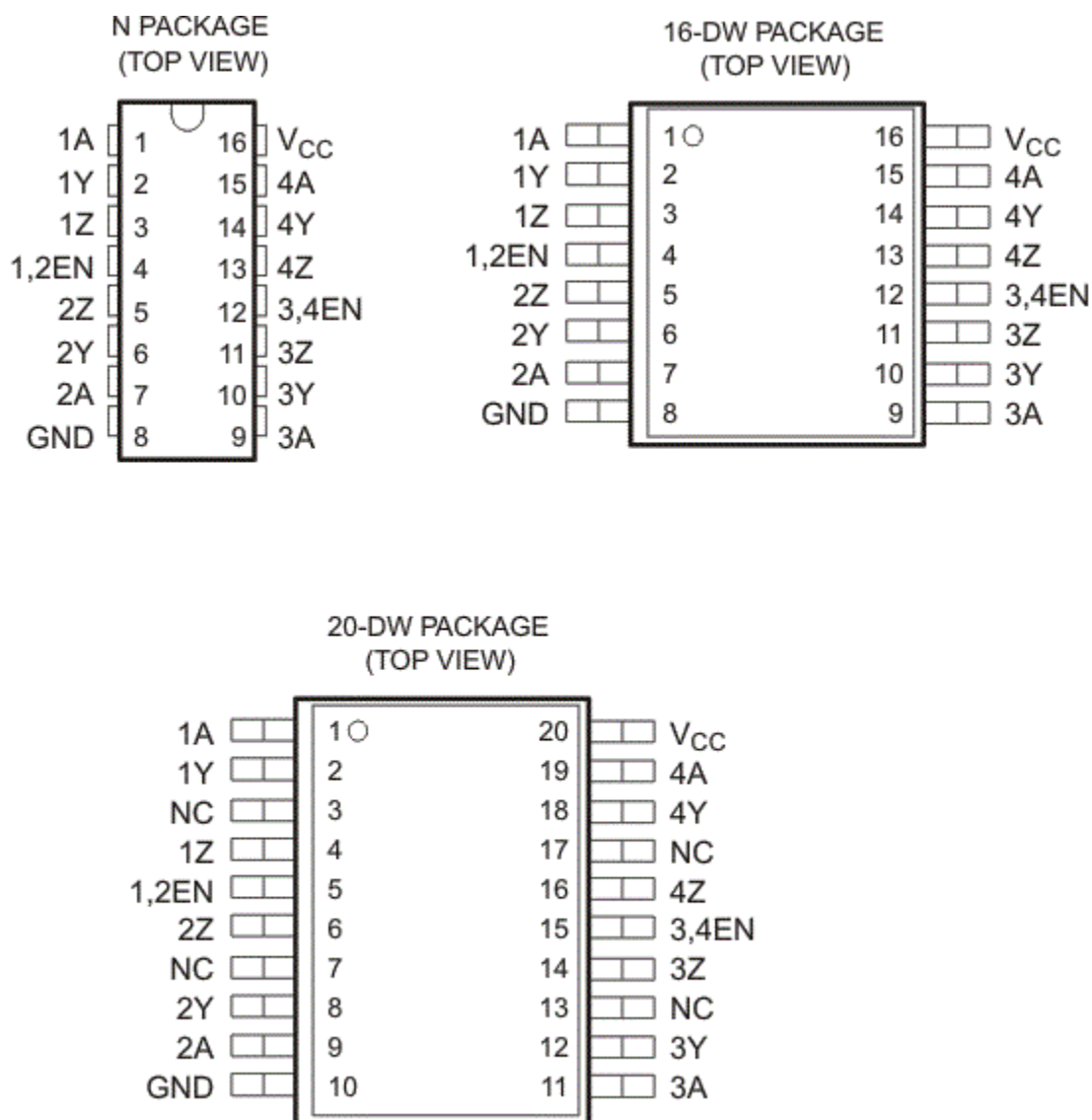
¹ 线路的信号传输速率是每秒进行电压转换的次数，以单位 bps (每秒位数) 来表示。



Table of Contents

1 特性	1	7 Device Functional Modes	13
2 应用	1	8 Application and Implementation	14
3 说明	1	8.1 Application Information.....	14
4 Pin Configuration and Functions	3	9 Device and Documentation Support	15
5 Specifications	4	9.1 接收文档更新通知.....	15
5.1 Absolute Maximum Ratings.....	4	9.2 支持资源.....	15
5.2 Dissipation Rating Table.....	4	9.3 Trademarks.....	15
5.3 Recommended Operating Conditions.....	4	9.4 静电放电警告.....	15
5.4 Thermal Information.....	5	9.5 术语表.....	15
5.5 Electrical Characteristics.....	6	10 Revision History	15
5.6 Switching Characteristics.....	6	11 Mechanical, Packaging, and Orderable	
5.7 Typical Characteristics.....	7	Information	16
6 Parameter Measure Information	8		

4 Pin Configuration and Functions



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			VALUE / UNIT
Supply voltage range, V_{CC} ⁽²⁾			– 0.3 V to 6 V
Voltage range at any bus (DC)			– 10 V to 15 V
Voltage range at any bus (transient pulse through 100 Ω , see 图 6-8)			– 30 V to 30 V
Input voltage range at any A or EN terminal, V_I			– 0.5 V to $V_{CC} + 0.5$ V
Electrostatic discharge	Human body model ⁽³⁾	Y, Z, and GND	± 12 kV
		All pins	± 5 kV
	Charged-device model ⁽⁴⁾	All pins	± 1 kV
Storage temperature range, T_{stg}			– 65°C to 150°C
Continuous power dissipation			See Dissipation Rating Table

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential I/O bus voltages, are with respect to GND.
- (3) Tested in accordance with JEDEC standard 22, Test Method A114-A.
- (4) Tested in accordance with JEDEC standard 22, Test Method C101.

5.2 Dissipation Rating Table

表 5-1. Dissipation Rating Table

PACKAGE ⁽¹⁾	JEDEC BOARD MODEL	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$ ⁽²⁾	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
16 DW	LOW K	1200 mW	9.6 mW/°C	769 mW	625 mW
	HIGH K	2240 mW	17.9 mW/°C	1434 mW	1165 mW
20 DW	LOW K	1483 mW	11.86 mW/°C	949 mW	771 mW
	HIGH K	2753 mW	22 mW/°C	1762 mW	1432 mW
16 N	LOW K	1150 mW	9.2 mW/°C	736 mW	598 mW

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
- (2) This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

5.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}		4.75	5	5.25	V
Voltage at any bus terminal	Y, Z	– 7		12	V
High-level input voltage, V _{IH}	A, EN	2		V _{CC}	V
Low-level input voltage, V _{IL}		0		0.8	
Output current		– 60		60	mA
Operating free-air temperature, T _A	SN75LBC174A	0		70	°C
	SN65LBC174A	– 40		85	

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾		SN75ALS174A			UNIT
		N (PDIP)	DW (SOIC)	DW	
		16 PINS	16 PINS	20 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	60.6	71.1	66.8	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	48.1	37.4	34.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	40.6	36.8	39.7	°C/W
ψ_{JT}	Junction-to-top characterization parameter	27.5	13.3	8.9	°C/W
ψ_{JB}	Junction-to-board characterization parameter	40.3	36.4	39	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

5.5 Electrical Characteristics

over recommended operating conditions

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IK}	Input clamp voltage	I _I = -18 mA		- 1.5	- 0.77		V
V _O	Open-circuit output voltage	Y or Z, No load		0		V _{CC}	V
V _{OD(SS)}	Steady-state differential output voltage magnitude ⁽²⁾	No load (open circuit)		3		V _{CC}	V
		R _L = 54Ω, See 图 6-1		1	1.6	2.5	
		With common-mode loading, See 图 6-2		1	1.6	2.5	
Δ V _{OD(SS)}	Change in steady-state differential output voltage between logic states	See 图 6-1		- 0.1		0.1	V
V _{OC(SS)}	Steady-state common-mode output voltage	See 图 6-3		2	2.4	2.8	V
Δ V _{OC(SS)}	Change in steady-state common-mode output voltage between logic states	See 图 6-3		- 0.02		0.02	V
I _I	Input current	A, EN		- 50		50	μ A
I _{OS}	Short-circuit output current	V _{TEST} = -7V to 12V, See 图 6-7	V _I = 0V	- 200		200	mA
			V _I = V _{CC}				
I _{OZ}	High-impedance-state output current		EN at 0V	- 50		50	μ A
I _{O(OFF)}	Output current with power off		V _{CC} = 0V	- 10		10	
I _{CC}	Supply current	V _I = 0V or V _{CC} , No load	All drivers enabled			23	mA
			All drivers disabled			1.5	
C _{IN}	Input Capacitance	A inputs			13		pF
		EN inputs			21		pF

(1) All typical values are at $V_{CC} = 5\text{V}$ and 25°C .

(2) The minimum V_{OD} may not fully comply with TIA/EIA-485-A at operating temperatures below 0°C . System designers should take the possibly lower output signal into account in determining the maximum signal transmission distance.

5.6 Switching Characteristics

over recommended operating conditions

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH}	Propagation delay time, low-to-high level output	$R_L = 54\Omega$, $C_L = 50\text{pF}$, See 图 6-4	5.5	8	11	ns
t_{PHL}	Propagation delay time, high-to-low level output		5.5	8	11	ns
t_r	Differential output voltage rise time		2	7.5	11	ns
t_f	Differential output voltage fall time		2	7.5	11	ns
$t_{sk(p)}$	Pulse skew $ t_{PLH} - t_{PHL} $			0.6	2	ns
				0.6	2	
$t_{sk(o)}$	Output skew ⁽¹⁾				2	ns
$t_{sk(pp)}$	Part-to-part skew ⁽²⁾				3	ns
t_{PZH}	Propagation delay time, high-impedance-to-high-level output	See 图 6-5			25	ns
t_{PHZ}	Propagation delay time, high-level-output-to-high impedance				25	ns
t_{PZL}	Propagation delay time, high-impedance-to-low-level output	See 图 6-6			30	ns
t_{PLZ}	Propagation delay time, low-level-output-to-high impedance				20	ns

(1) Output skew ($t_{sk(o)}$) is the magnitude of the time delay difference between the outputs of a single device with all of the inputs connected together.

(2) Part-to-part skew ($t_{sk(pp)}$) is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same input signals, the same supply voltages, at the same temperature, and have identical packages and test circuits.

5.7 Typical Characteristics

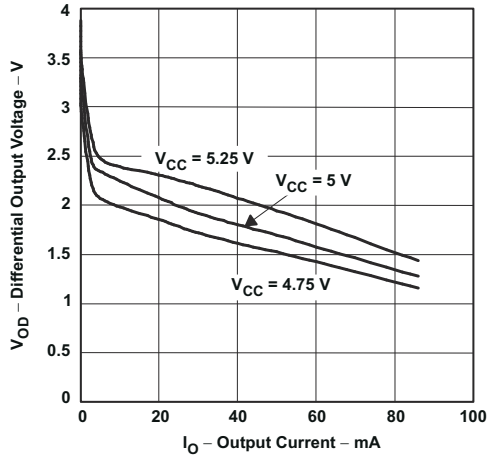


图 5-1. Differential Output Voltage vs Output Current

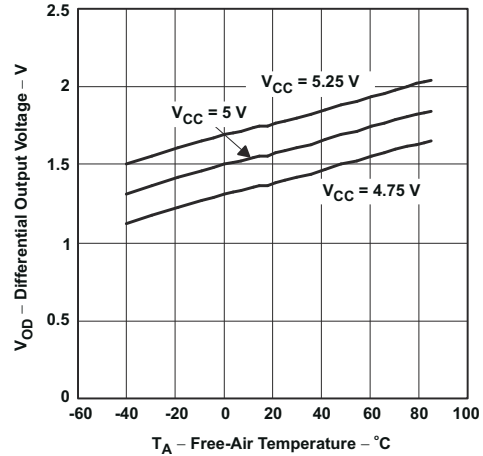


图 5-2. Differential Output Voltage vs Free-air Temperature

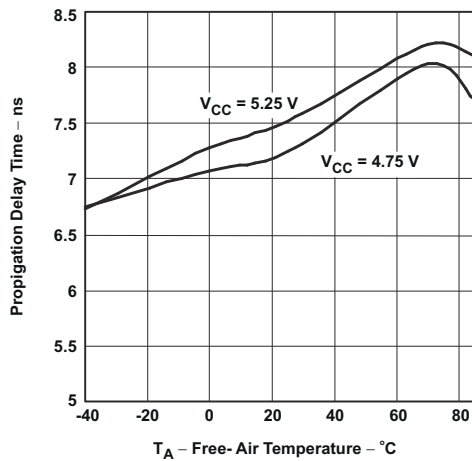


图 5-3. Propagation Delay Time vs Free-air Temperature

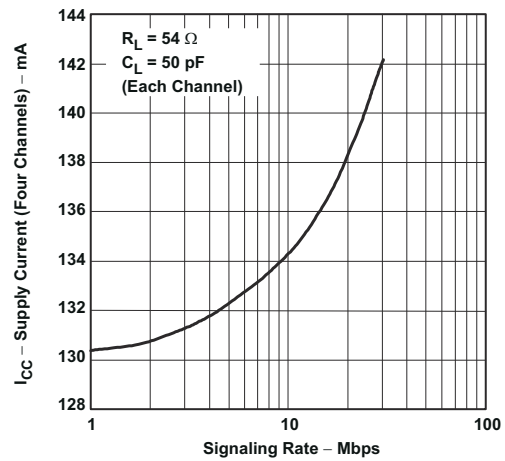


图 5-4. Supply Current (Four Channels) vs Signaling Rate

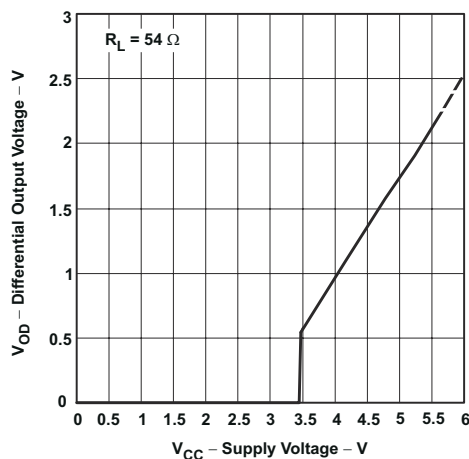


图 5-5. Differential Output Voltage vs Supply Voltage

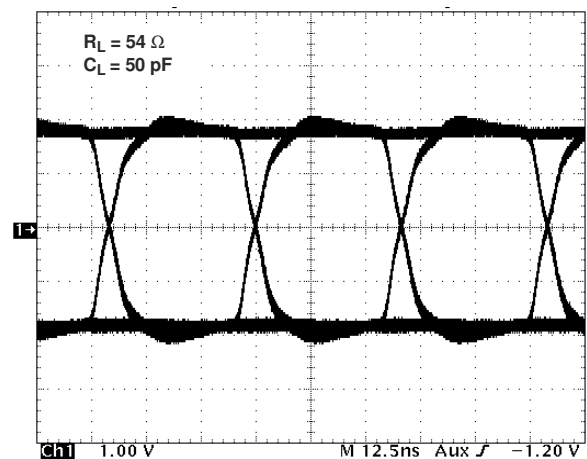


图 5-6. Eye Pattern, Pseudorandom Data at +30Mbps

6 Parameter Measure Information

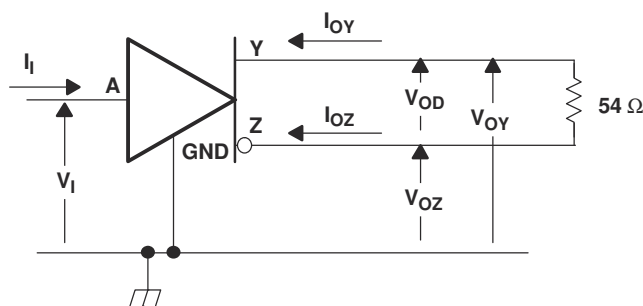


图 6-1. Test Circuit, V_{OD} Without Common-Mode Loading

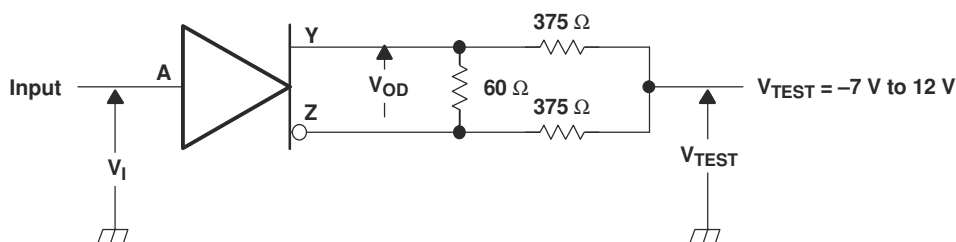
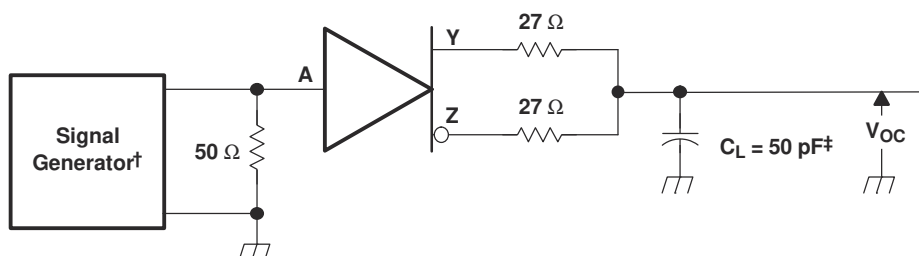


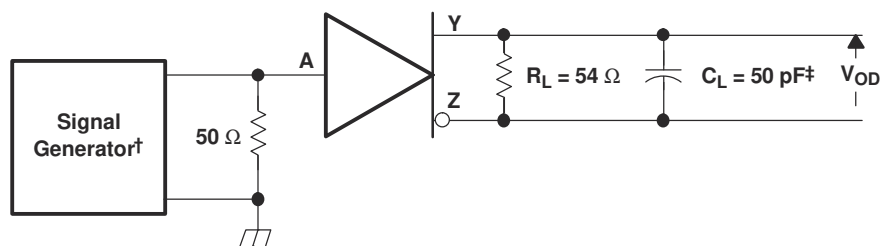
图 6-2. Test Circuit, V_{OD} With Common-Mode Loading



† PRR = 1 MHz, 50% Duty Cycle, $t_r < 6$ ns, $t_f < 6$ ns, $Z_O = 50 \Omega$

‡ Includes probe and jig capacitance

图 6-3. V_{OC} Test Circuit



† PRR = 1 MHz, 50% Duty Cycle, $t_r < 6$ ns, $t_f < 6$ ns, $Z_O = 50 \Omega$

‡ Includes probe and jig capacitance

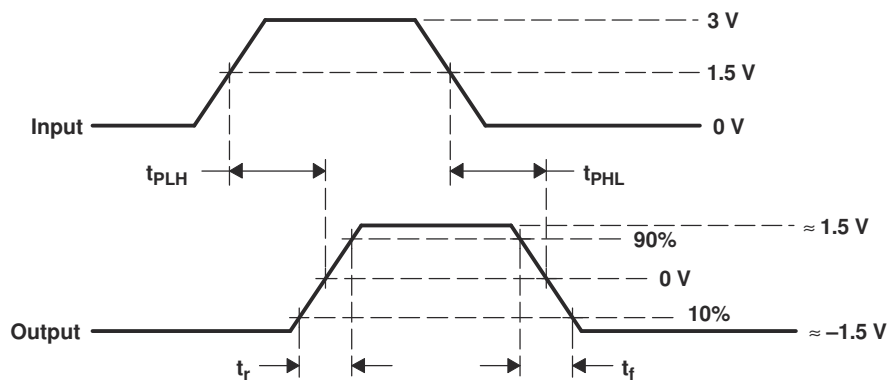
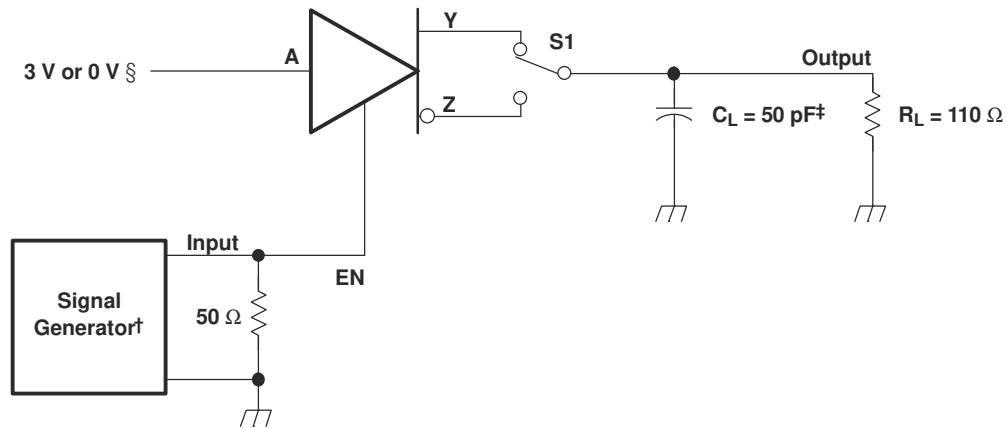


图 6-4. Output Switching Test Circuit and Waveforms



† PRR = 1 MHz, 50% Duty Cycle, $t_r < 6 \text{ ns}$, $t_f < 6 \text{ ns}$, $Z_O = 50 \text{ } \Omega$

‡ Includes probe and jig capacitance

§ 3 V if testing Y output, 0 V if testing Z output

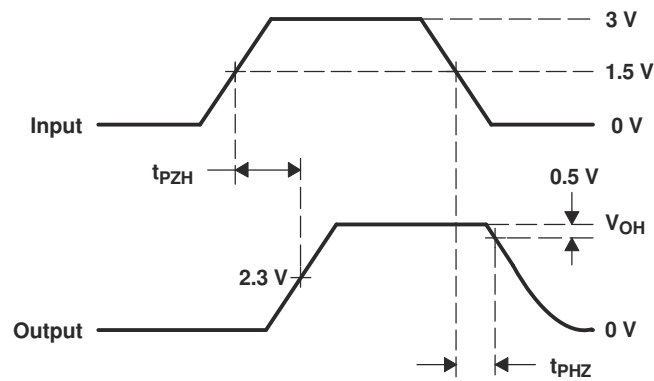
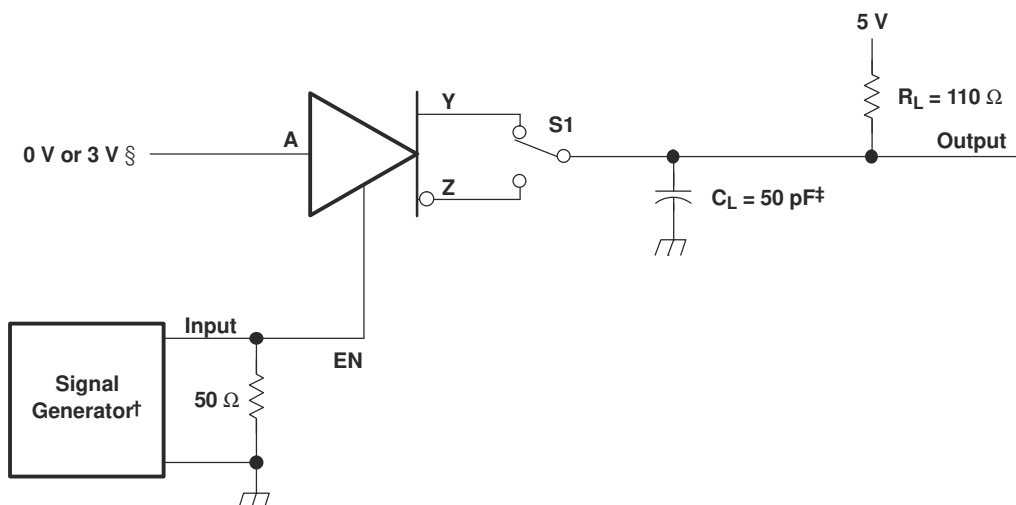


图 6-5. Enable Timing Test Circuit and Waveforms, t_{PZH} and t_{PHZ}



† PRR = 1 MHz, 50% Duty Cycle, $t_r < 6$ ns, $t_f < 6$ ns, $Z_O = 50 \Omega$

‡ Includes probe and jig capacitance

§ 3 V if testing Y output, 0 V if testing Z output

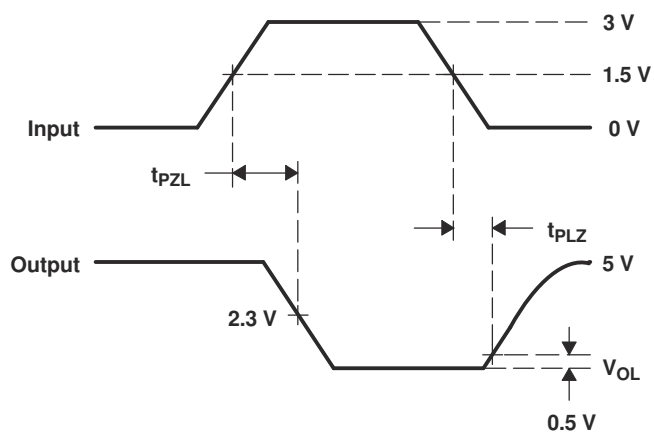


图 6-6. Enable Timing Test Circuit and Waveforms, t_{PZL} and t_{PLZ}

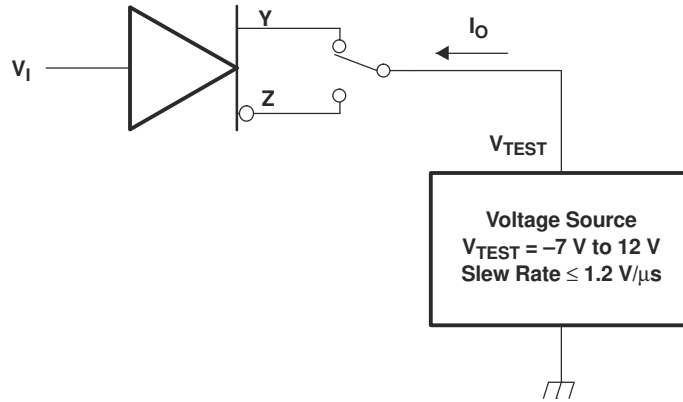


图 6-7. Test Circuit, Short-Circuit Output Current

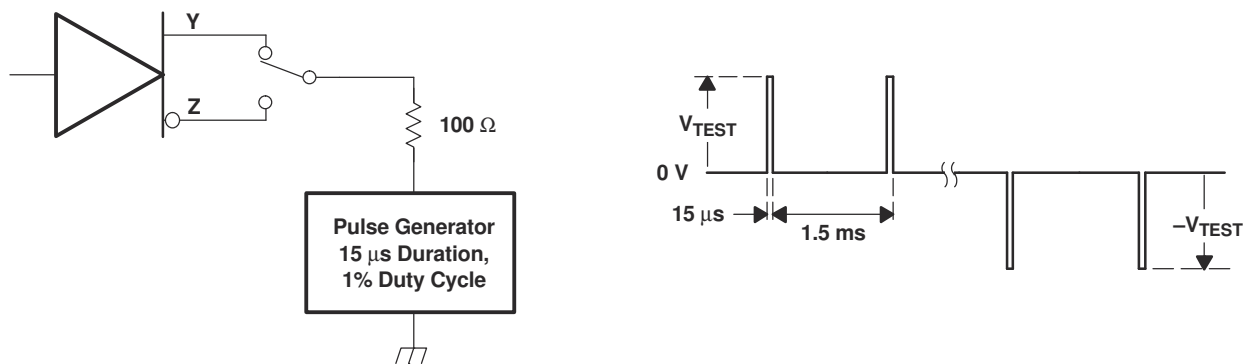


图 6-8. Test Circuit Waveform, Transient Overvoltage Test

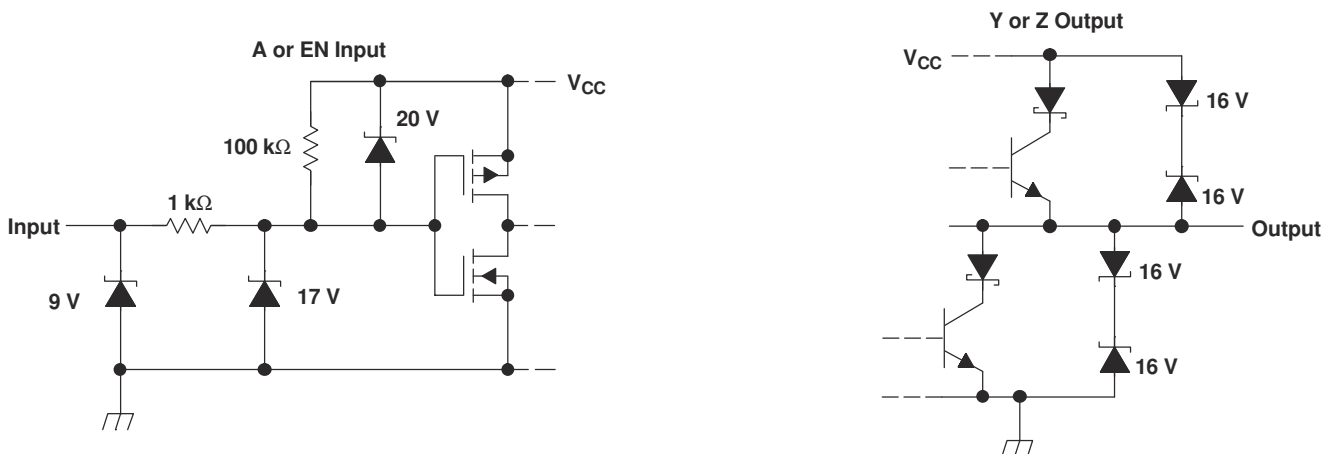


图 6-9. Equivalent Input and Output Schematic Diagrams

7 Device Functional Modes

表 7-1. Function table (each driver)

INPUT ⁽¹⁾	ENABLE	OUTPUT	OUTPUT
A	EN	Y	Z
L	H	L	H
H	H	H	L
OPEN	H	H	L
L	OPEN	L	H
H	OPEN	H	L
OPEN	OPEN	H	L
X	L	Z	Z

(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off)

8 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

8.1 Application Information

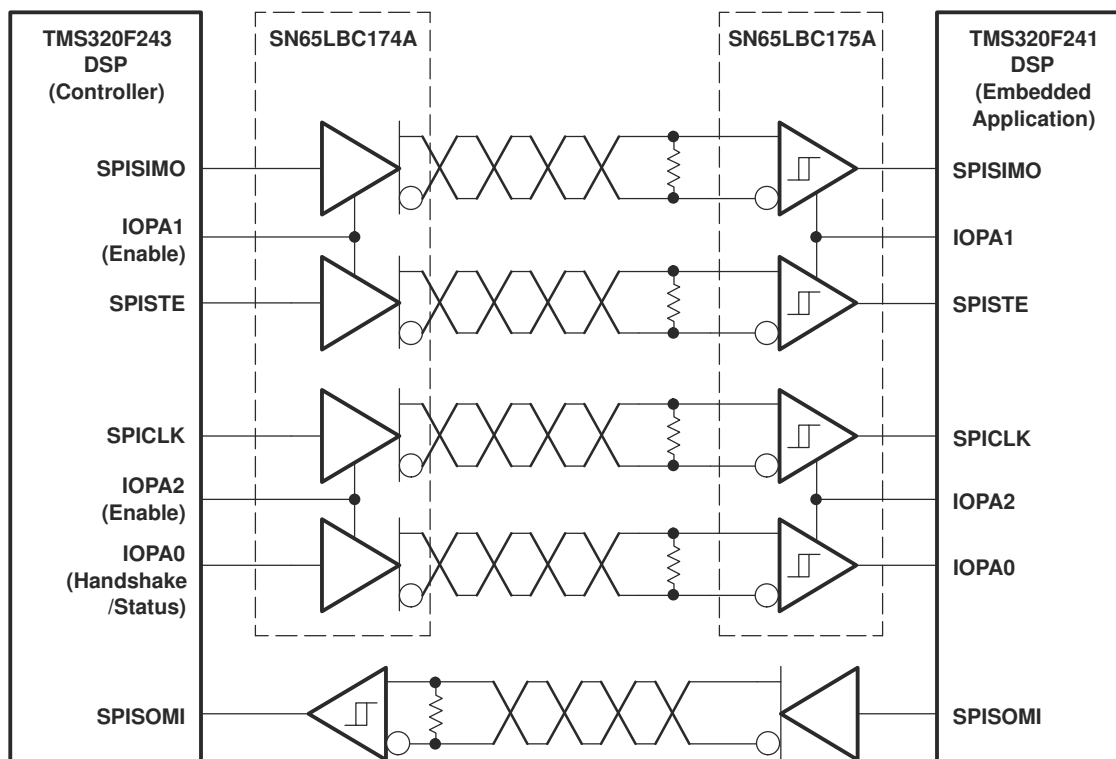


图 8-1. Typical Application Circuit, DSP-to-DSP Link via Serial Peripheral Interface

9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击 [通知](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

9.2 支持资源

[TI E2E™ 中文支持论坛](#) 是工程师的重要参考资料，可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题，获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的 [使用条款](#)。

9.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

LinBiCMOS® is a registered trademark of Texas Instruments.

所有商标均为其各自所有者的财产。

9.4 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

9.5 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

10 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision F (October 2009) to Revision G (April 2024)	Page
• 更改了整个文档中的表格、图和交叉参考的编号格式.....	1
• Added the <i>Thermal Information</i> table.....	5

Changes from Revision E (July 2008) to Revision F (October 2009)	Page
• Added C _{IN} - Input Capacitance to the Electrical Characteristics table.....	6
• Changed the location of 图 6-9	8
• Changed 表 7-1 header From: ENABLE G To: ENABLE EN.....	13

Changes from Revision D (June 2008) to Revision E (July 2008)	Page
• 将“特性”要点从“输出 ESD 保护超过 11 kV”更改为“输出 ESD 保护：12kV”	1
• Changed Electrostatic discharge-Human body model-Y, Z, and GND From: 11kV To: 12kV.....	4
• From: A, G, $\bar{G}$ To: A, EN.....	6

Changes from Revision C (June 2008) to Revision D (July 2008)	Page
• Changed Electrostatic discharge-Human body model-Y, Z, and GND From: 13kV To: 11kV.....	4
• Changed the <i>Dissipation Rating Table</i>	4

Changes from Revision B (June 2001) to Revision C (May 2003)	Page
• 将“特性”要点从“输出 ESD 保护超过 13kV”更改为“输出 ESD 保护 : 11kV”	1
• 将业界通用的“特性”要点从“与 SN75174、MC3487 和 DS96174 兼容”更改为“与 SN75174、MC3487、DS96174、LTC487 和 MAX3042 兼容”	1

Changes from Revision A (February 2001) to Revision B (June 2001)	Page
• Changed DW Package appearance.....	3
• Added 图 5-5	7

Changes from Revision * (October 2000) to Revision A (February 2001)	Page
• 更改了整个数据表中的多个项目	1

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN65LBC174A16DW	LIFEBUY	SOIC	DW	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65LBC174A	
SN65LBC174A16DWR	ACTIVE	SOIC	DW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65LBC174A	Samples
SN65LBC174A16DWRG4	ACTIVE	SOIC	DW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65LBC174A	Samples
SN65LBC174ADWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	65LBC174A	Samples
SN65LBC174AN	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	65LBC174A	Samples
SN75LBC174ADW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75LBC174A	Samples
SN75LBC174ADWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	75LBC174A	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

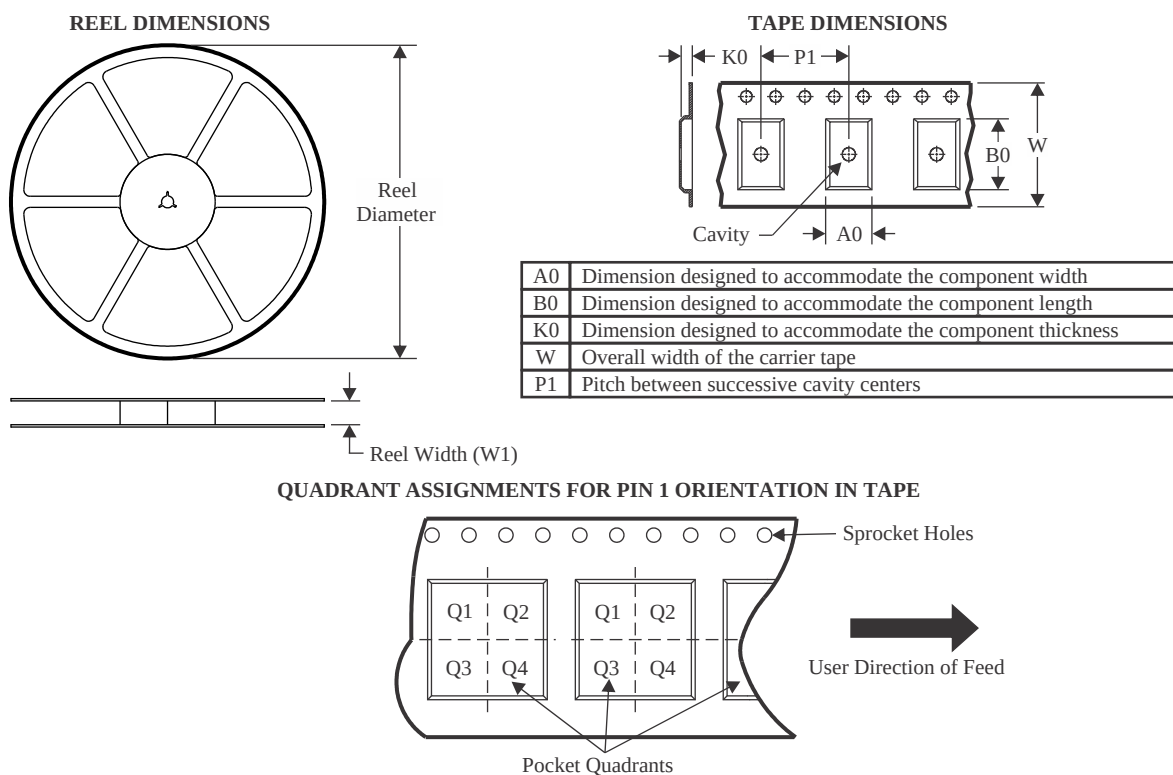
OTHER QUALIFIED VERSIONS OF SN65LBC174A :

- Enhanced Product : [SN65LBC174A-EP](#)

NOTE: Qualified Version Definitions:

- Enhanced Product - Supports Defense, Aerospace and Medical Applications

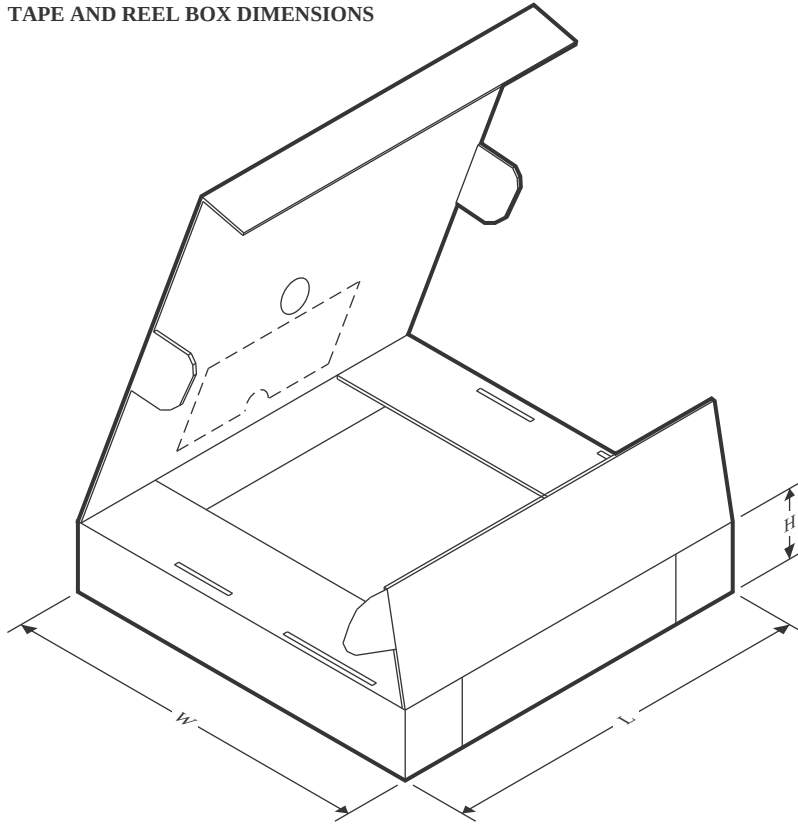
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LBC174A16DWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
SN65LBC174ADWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN75LBC174A16DWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
SN75LBC174ADWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

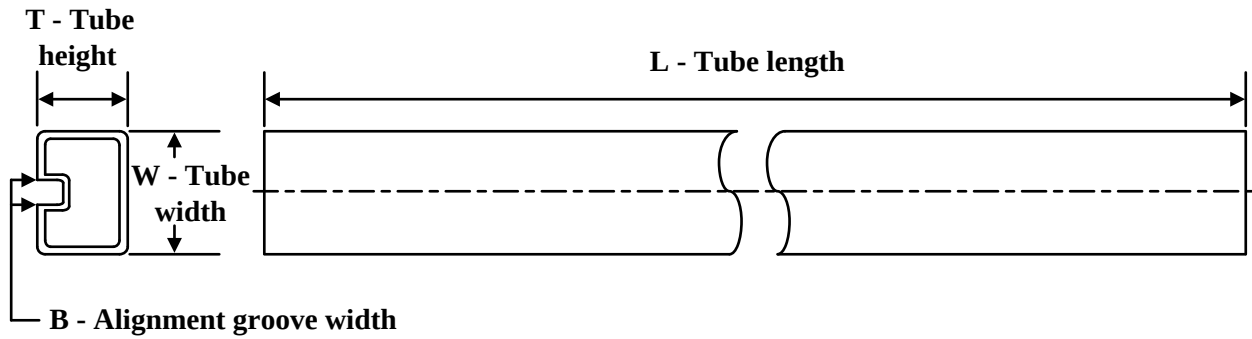
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LBC174A16DWR	SOIC	DW	16	2000	350.0	350.0	43.0
SN65LBC174ADWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN75LBC174A16DWR	SOIC	DW	16	2000	350.0	350.0	43.0
SN75LBC174ADWR	SOIC	DW	20	2000	350.0	350.0	43.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN65LBC174A16DW	DW	SOIC	16	40	506.98	12.7	4826	6.6
SN65LBC174ADW	DW	SOIC	20	25	506.98	12.7	4826	6.6
SN65LBC174ADW	DW	SOIC	20	25	507	12.83	5080	6.6
SN65LBC174AN	N	PDIP	16	25	506	13.97	11230	4.32
SN75LBC174A16DW	DW	SOIC	16	40	506.98	12.7	4826	6.6
SN75LBC174ADW	DW	SOIC	20	25	506.98	12.7	4826	6.6
SN75LBC174ADW	DW	SOIC	20	25	507	12.83	5080	6.6
SN75LBC174AN	N	PDIP	16	25	506	13.97	11230	4.32

GENERIC PACKAGE VIEW

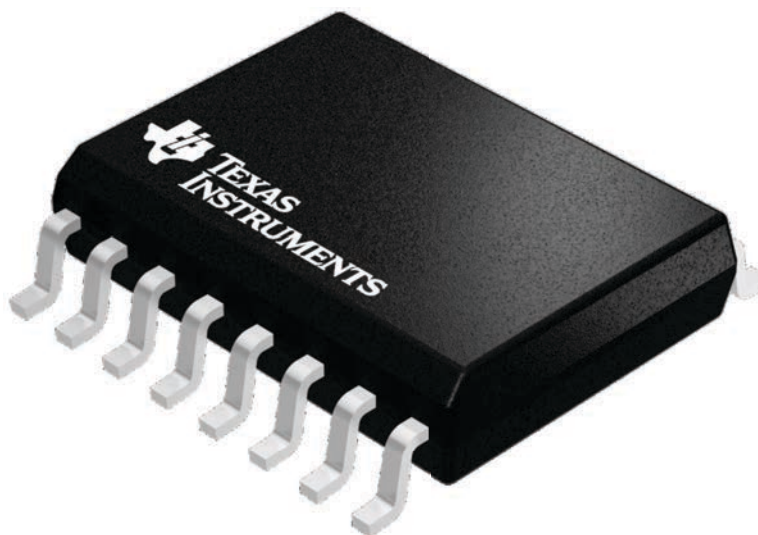
DW 16

SOIC - 2.65 mm max height

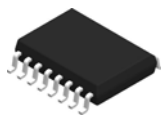
7.5 x 10.3, 1.27 mm pitch

SMALL OUTLINE INTEGRATED CIRCUIT

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4224780/A

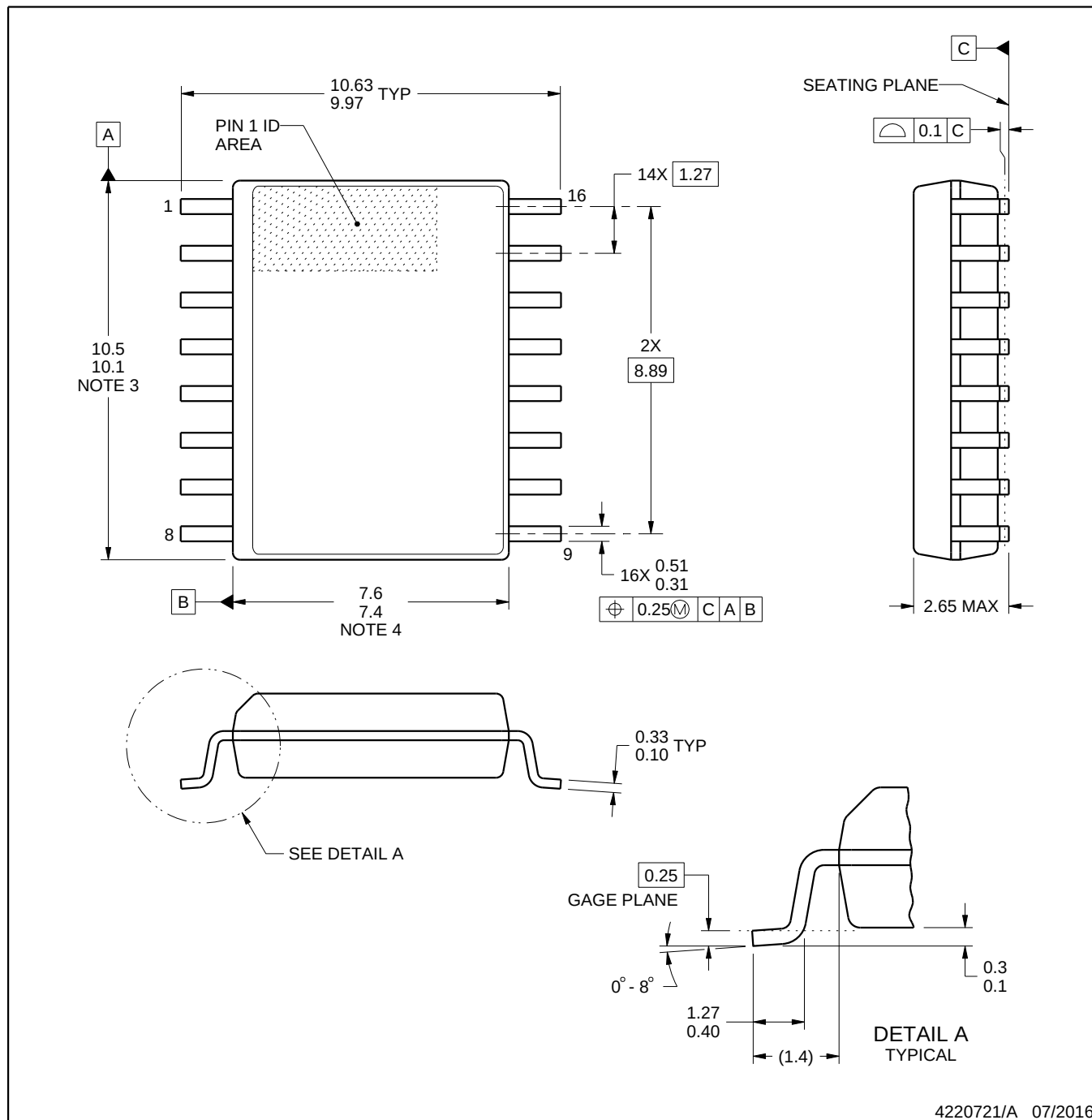


DW0016A

PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



4220721/A 07/2016

NOTES:

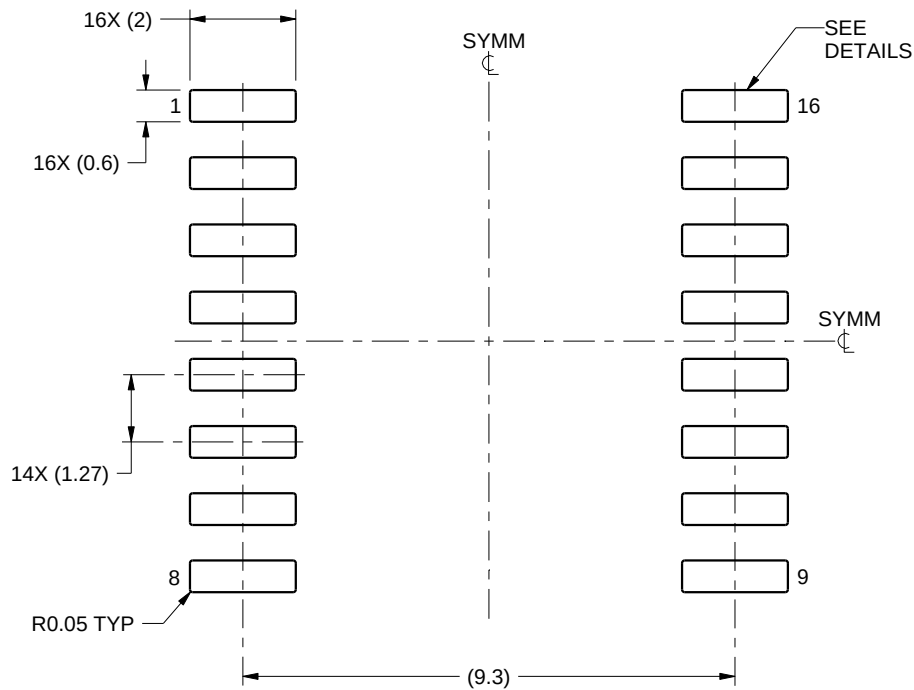
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
5. Reference JEDEC registration MS-013.

EXAMPLE BOARD LAYOUT

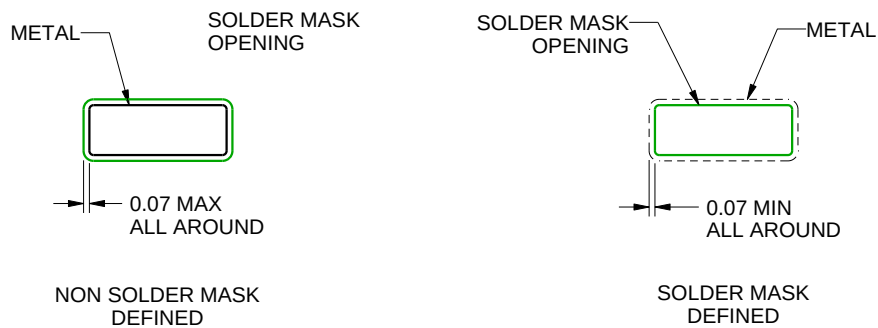
DW0016A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE
SCALE:7X



SOLDER MASK DETAILS

4220721/A 07/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

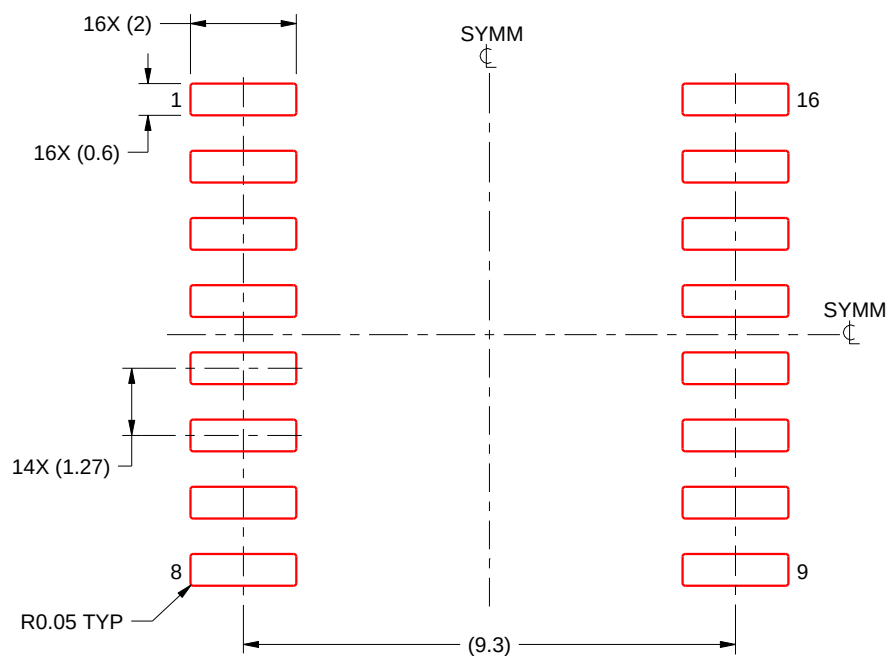
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DW0016A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:7X

4220721/A 07/2016

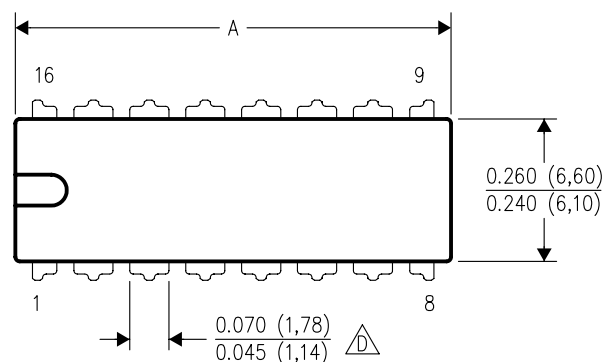
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

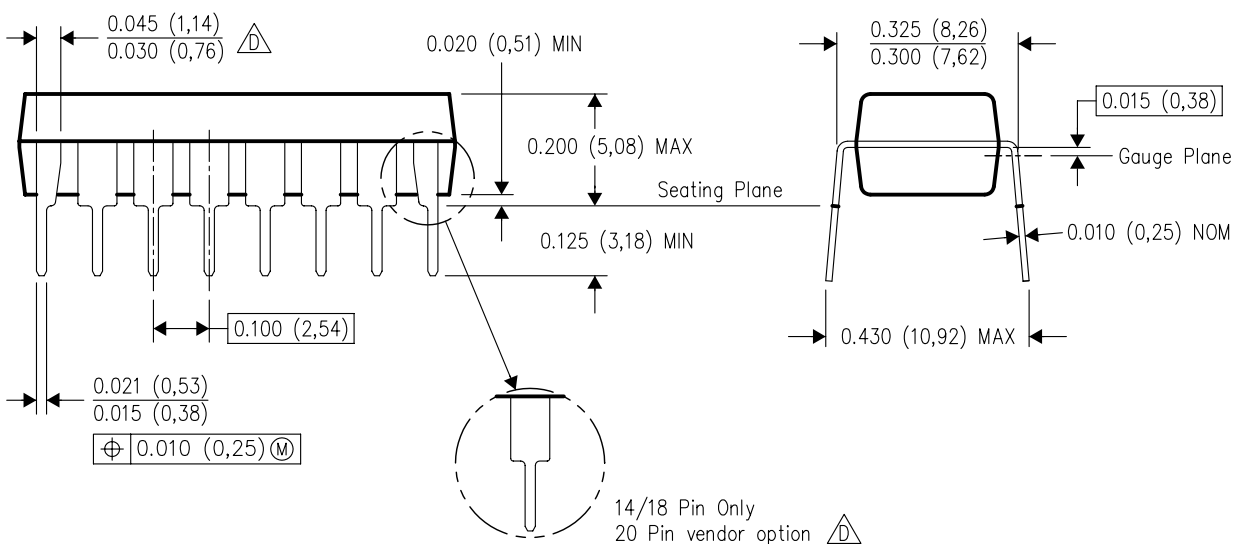
N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



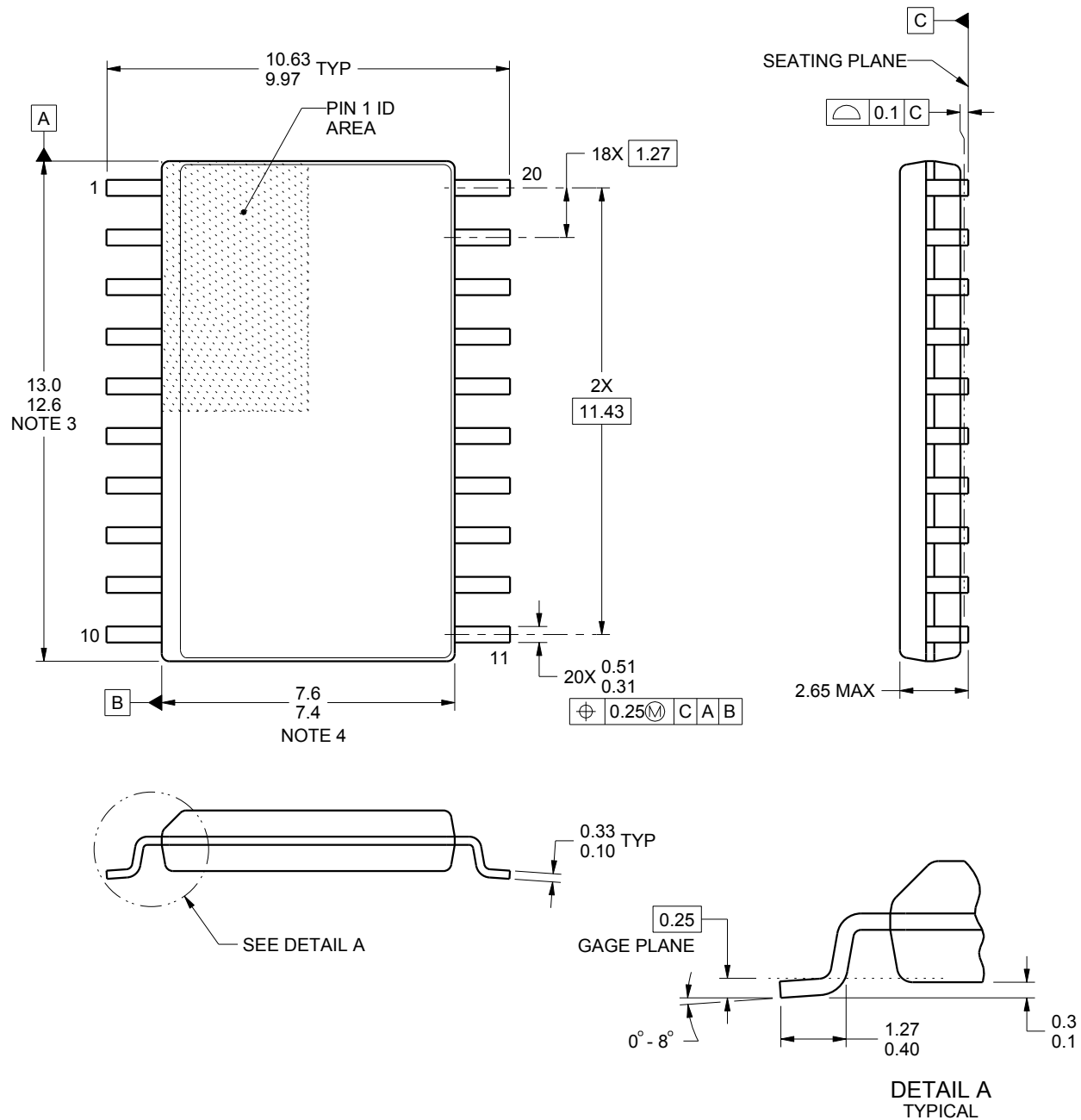
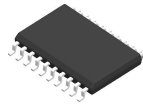
PINS ** DIM	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



4040049/E 12/2002

NOTES:

- A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
-  Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 The 20 pin end lead shoulder width is a vendor option, either half or full width.



4220724/A 05/2016

NOTES:

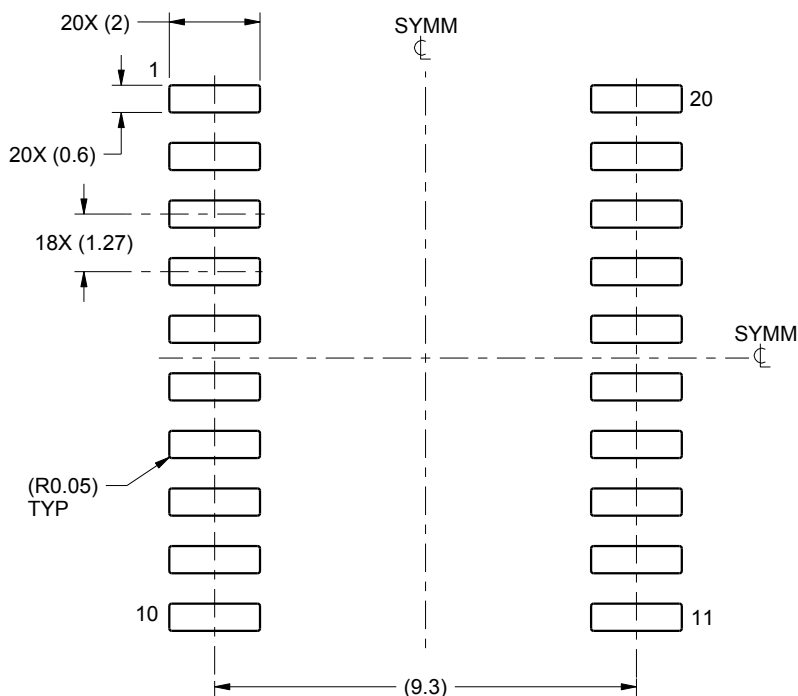
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
5. Reference JEDEC registration MS-013.

EXAMPLE BOARD LAYOUT

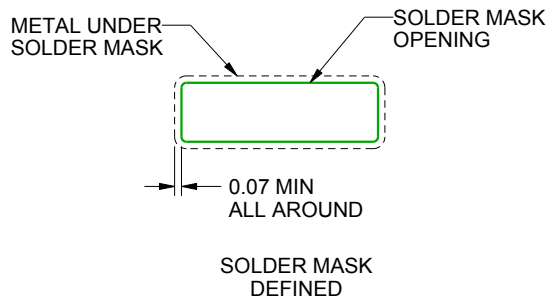
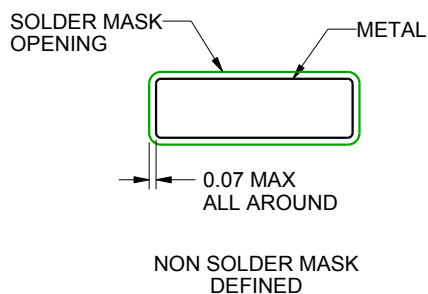
DW0020A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE
SCALE:6X



SOLDER MASK DETAILS

4220724/A 05/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

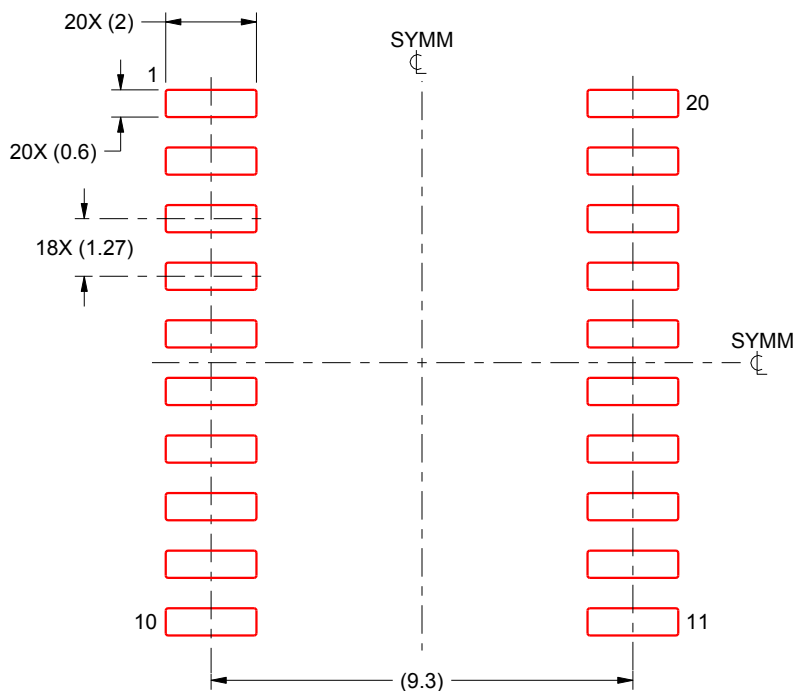
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DW0020A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:6X

4220724/A 05/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

重要声明和免责声明

TI“按原样”提供技术和可靠性数据（包括数据表）、设计资源（包括参考设计）、应用或其他设计建议、网络工具、安全信息和其他资源，不保证没有瑕疵且不做任何明示或暗示的担保，包括但不限于对适销性、某特定用途方面的适用性或不侵犯任何第三方知识产权的暗示担保。

这些资源可供使用 TI 产品进行设计的熟练开发人员使用。您将自行承担以下全部责任：(1) 针对您的应用选择合适的 TI 产品，(2) 设计、验证并测试您的应用，(3) 确保您的应用满足相应标准以及任何其他功能安全、信息安全、监管或其他要求。

这些资源如有变更，恕不另行通知。TI 授权您仅可将这些资源用于研发本资源所述的 TI 产品的应用。严禁对这些资源进行其他复制或展示。您无权使用任何其他 TI 知识产权或任何第三方知识产权。您应全额赔偿因在这些资源的使用中对 TI 及其代表造成的任何索赔、损害、成本、损失和债务，TI 对此概不负责。

TI 提供的产品受 [TI 的销售条款](#) 或 [ti.com](#) 上其他适用条款/TI 产品随附的其他适用条款的约束。TI 提供这些资源并不会扩展或以其他方式更改 TI 针对 TI 产品发布的适用的担保或担保免责声明。

TI 反对并拒绝您可能提出的任何其他或不同的条款。

邮寄地址：Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2024，德州仪器 (TI) 公司